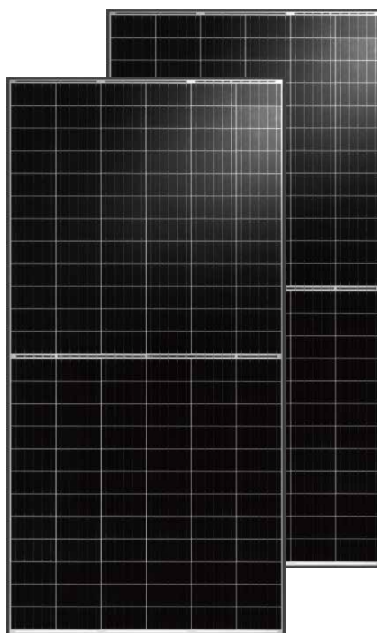


BISTAR

TP6H72M
TP6H72M(H) **144 half-cell**

390 - 410W

PERC



产品特性



半片电池技术



显著降低热斑风险



更低度电成本

2%



Anti
PID

优秀的抗PID性能

TUV
85 /85% RH 192

PID



IP68接线盒

体系及产品认证

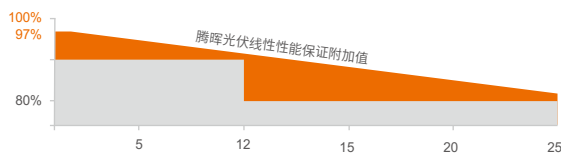
- IEC 61215 / IEC 61730 / UL 1703
- ISO 9001: 2015
- ISO 14001: 2015
- ISO 45001: 2018



质量保证

12
质量保证

25
功率保证



电性能参数

STC		0 ~ +3%						
(Pmax/W)		390	395	400	405	410		
(Vmpp/V)		40.0	40.3	40.5	40.7	40.9		
(Impp/A)		9.70	9.81	9.88	9.96	10.03		
(Voc/V)		48.7	49.0	49.2	49.3	49.5		
(Isc/A)		10.35	10.41	10.48	10.56	10.63		
m(%)		19.4	19.6	19.9	20.1	20.4		
NMOT								
(Pmax/W)		290	294	298	302	305		
(Vmpp/V)		37.1	37.4	37.6	37.7	37.9		
(Impp/A)		7.93	7.88	7.94	8.01	8.07		
(Voc/V)		45.4	45.6	45.8	45.9	46.1		
(Isc/A)		8.35	8.40	8.46	8.52	8.58		
STC	1000W/	25	AM1.5	NMOT	800W/	20	AM1.5	1m/s

机械参数

	158.75*158.75mm
	144 (6*24)
	22.5kg (49.06lbs)
	2008*1002*35mm (79.06*39.45*1.38inches)
	300mm (11.81inches)
	TUV: 4mm ² (0.006inches ²)/UL: 12AWG
	3.2mm
	3/6
(1)	31 / 682 /40
(2)	31 +4 / 726 /40
	IP68

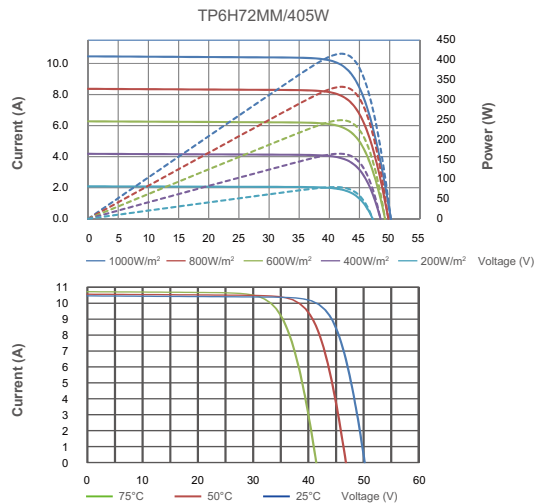
工作条件

	1000V/1500V/DC(IEC)
	-40°C ~ +85°C
	20A
	: 5400Pa/ : 2400Pa
	0.1
	II
	100M
	T01/LJQ-3-CSY/MC4/MC4-EVO2

温度特性

Pmax	-0.36%/°C
Voc	-0.26%/°C
Isc	+0.043%/°C
NMOT	43± 2°C

I-V曲线



技术图

